SPECIFICATION

Please replace the paragraph beginning at page 1, line13 with the following:

A flash memory device is a nonvolatile high-density data storage device that can write and erase data [[on an]] on-board. A flash memory cell includes a field effect transistor (FET) having a selection gate, a floating gate, a source and a drain. Data is stored in the flash memory cell by variations in the amount of charge stored in the floating gate, which causes a variation in a threshold voltage (Vt) of the flash memory cell. The data stored in the flash memory cell is read out by applying a selection voltage to a word line connected to the selection gate. The amount of current, which flows when the flash memory cell is selected, is determined by the threshold voltage (Vt) of the flash memory cell.